

C2D05120E **Silicon Carbide Schottky Diode**

ZERO RECOVERY® RECTIFIER

 \mathbf{V}_{RRM} 1200 V $I_{\rm F}$ ($T_{\rm c}$ =135°C) = 8.5 A 28 nC Q_c

Features

- 1.2kV Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

PIN 2O-

Package

TO-252-2

PIN 1O-O CASE

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- **Motor Drives**
- High Voltage Multipliers

Part Number	Package	Marking
C2D05120E	TO-252-2	C2D05120

Halogen-Free

Maximum Ratings (T_C=25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{RRM}	Repetitive Peak Reverse Voltage	1200	V		
V_{RSM}	Surge Peak Reverse Voltage	1200	V		
V _{DC}	DC Blocking Voltage	1200	V		
I _F	Continuous Forward Current	17.5 8.5 5	А	T _c =25°C T _c =135°C T _c =157°C	
\boldsymbol{I}_{FRM}	Repetitive Peak Forward Surge Current	30	А	T_c =25°C, t_p =10 ms, Half Sine Wave	
\mathbf{I}_{FSM}	Non-Repetitive Peak Forward Surge Current	100	А	T _c =25°C, t _p =10 µs, Pulse	
P _{tot}	Power Dissipation	136 59	W	T _c =25°C T _c =110°C	
$T_{_{\mathtt{J}}}$, $T_{_{\mathtt{stg}}}$	Operating Junction and Storage Temperature	-55 to +175	°C		



Electrical Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Voltage	1.6 2.6	1.8 3.0	V	$I_F = 5 \text{ A } T_J = 25^{\circ}\text{C}$ $I_F = 5 \text{ A } T_J = 175^{\circ}\text{C}$	
I _R	Reverse Current	50 100	200 1000	μΑ	$V_R = 1200 \text{ V } T_J = 25^{\circ}\text{C}$ $V_R = 1200 \text{ V } T_J = 150^{\circ}\text{C}$	
Q _c	Total Capacitive Charge	28		nC	$V_R = 1200 \text{ V, } I_F = 5 \text{ A}$ $di/dt = 500 \text{ A/}\mu\text{s}$ $T_J = 25^{\circ}\text{C}$	
С	Total Capacitance	455 45 33		pF	$V_R = 0 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$ $V_R = 200 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$ $V_R = 400 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$	

Note:

Thermal Characteristics

Symbol	Parameter	Тур.	Unit
$R_{_{ heta JC}}$	Thermal Resistance from Junction to Case	1.1	°C/W

Typical Performance

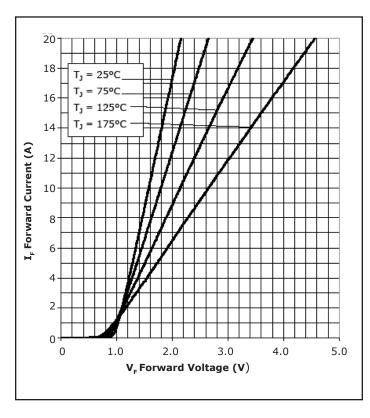


Figure 1. Forward Characteristics

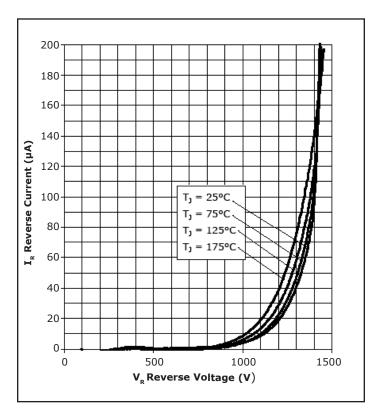
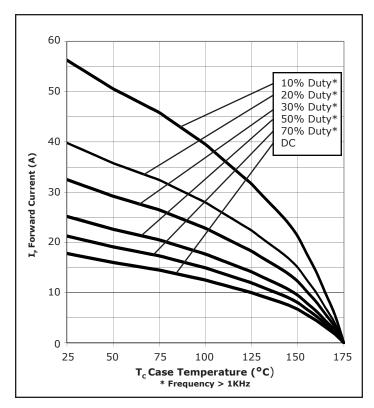


Figure 2. Reverse Characteristics

^{1.} This is a majority carrier diode, so there is no reverse recovery charge.



Typical Performance



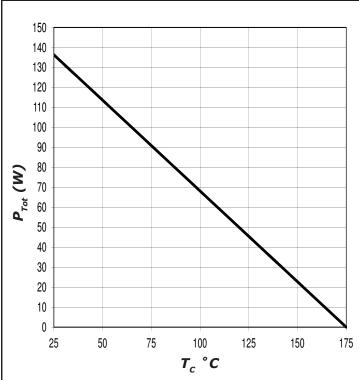


Figure 3. Current Derating

Figure 4. Power Derating

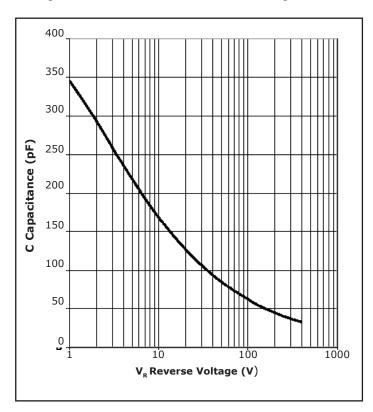


Figure 5. Capacitance vs. Reverse Voltage



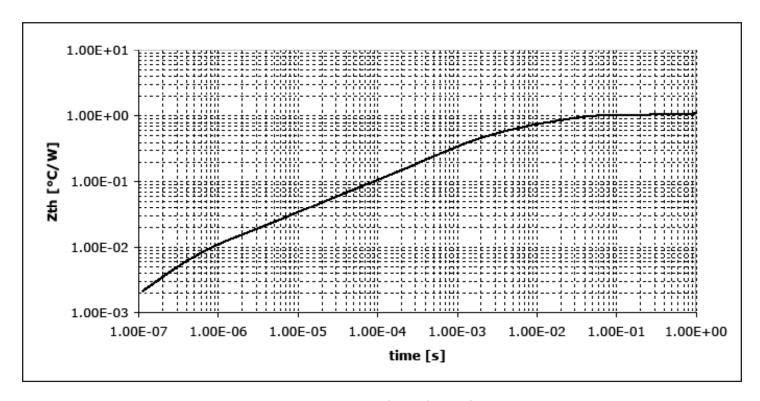
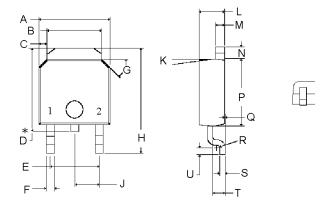


Figure 6. Transient Thermal Impedance



Package Dimensions

Package TO-252-2

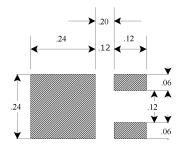




POC	Inc	hes	Millimeters		
POS	Min	Max	Min	Max	
Α	.250	.289	6.350	7.341	
В	.197	.215	5.004	5.461	
С	.027	.050	.686	1.270	
D*	.270	.322	6.858	8.179	
E	.178	.182	4.521	4.623	
F	.025	.045	.635	1.143	
G	44°	46°	44°	46°	
Н	.380	.410	9.652	10.414	
J	.090 TYP		2.286 TYP		
K	6°	8°	6°	8°	
L	.086	.094	2.184	2.388	
М	.018	.034	.457	.864	
N	.035	.050	.889	1.270	
Р	.231	.246	5.867	6.248	
Q	0.00	.005	0.00	.127	
R	R0.010 TYP		R0.254 TYP		
S	.017	.023	.432	.584	
Т	.038	.045	.965	1.143	
U	.021	.029	.533	.737	

Note:

Recommended Solder Pad Layout



TO-252-2

**All dimensions in mils

Part Number	Package	Marking
C2D05120E	TO-252-2	C2D05120

Note: Recommended soldering profiles can be found in the applications note here: http://www.cree.com/power_app_notes/soldering



^{*} Tab "D" may not be present



Notes

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented January 2, 2013. RoHS Declarations for this product can be obtained from your Cree representative or from the Product Documentation sections of www.cree.com.

REACh Compliance

REACh substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a Cree representative to insure you get the most up-to-date REACh SVHC Declaration. REACh banned substance information (REACh Article 67) is also available upon request.

• This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, air traffic control systems, or weapons systems.